

### 4 Watt Ka Band Packaged Amplifier



#### **Product Description**

The TriQuint TGA4905-CP is a compact 4 Watt High Power Amplifier Packaged MMIC for Ka-band applications. The part is designed using TriQuint's proven standard 0.25 um gate Power pHEMT production process.

The TGA4905 provides a nominal 36 dBm of output power at an input power level of 18 dBm from 25-31 GHz with a small signal gain of 22 dB.

The part is ideally suited for low cost emerging markets such as base station transmitters for satellite ground terminals, point to point radio and LMDS.

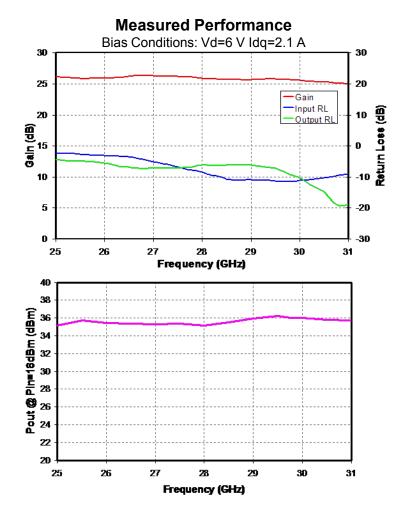
The TGA4905-CP is 100% RF tested to ensure performance compliance.

#### **Key Features and Performance**

- 36 dBm VSAT band Psat
- 22 dB Nominal Gain
- 25 31 GHz Frequency Range
- 0.25µm pHEMT Technology
- Bias Conditions: 6 V, 2.1 A (Quiescent) up to 4 A under RF drive
- Package Dimensions:
  13.34 x 9.65 x 1.85 mm
  (0.525 x 0.380 x 0.073 in)

#### **Primary Applications**

- Satellite Ground Terminals
- Point to Point



Datasheet subject to change without notice



#### TABLE I MAXIMUM RATINGS

Symbol	Parameter <u>1</u> /	Value	Notes
VD	Drain Voltage	8 V	<u>2</u> /
V <sub>G</sub>	Gate Voltage Range	-5 V to 0 V	
I <sub>D</sub>	Drain Current (Quiescent)	3.0 A	<u>2</u> /
I <sub>G</sub>	Gate Current	62 mA	
P <sub>IN</sub>	Input Continuous Wave Power	24 dBm	<u>2</u> /
PD	Power Dissipation	28 W	<u>2</u> / <u>3</u> /
Т <sub>сн</sub>	Operating Channel Temperature	200 °C	<u>4/ 5</u> /
	Mounting Temperature (30 Seconds)	320 °C	
T <sub>STG</sub>	Storage Temperature	-65 to 150 °C	

- 1/ These ratings represent the maximum operable values for this device.
- 2/ Combinations of supply voltage, supply current, input power, and output power shall not exceed P<sub>D</sub>.
- 3/ When operated at this power dissipation with a baseplate temperature of 70 °C, the median life is 7.3E3 hours.
- <u>4</u>/ These ratings apply to each individual FET.
- 5/ Junction operating temperature will directly affect the device median time to failure (Tm). For maximum life, it is recommended that junction temperatures be maintained at the lowest possible levels.



#### TABLE II RF CHARACTERIZATION TABLE $(T_A = 25^{\circ}C, Nominal)$ (Vd = 6 V, Idq = 2.1 A)

SYMBOL	PARAMETER	TEST CONDITION	TYPICAL	UNITS
Gain	Small Signal Gain	F = 25 – 31GHz	22	dB
IRL	Input Return Loss	F = 25 – 31GHz	10	dB
ORL	Output Return Loss	F = 25 – 31GHz	8	dB
PWR	Output Power @ Psat	F = 25 – 31GHz	36	dBm

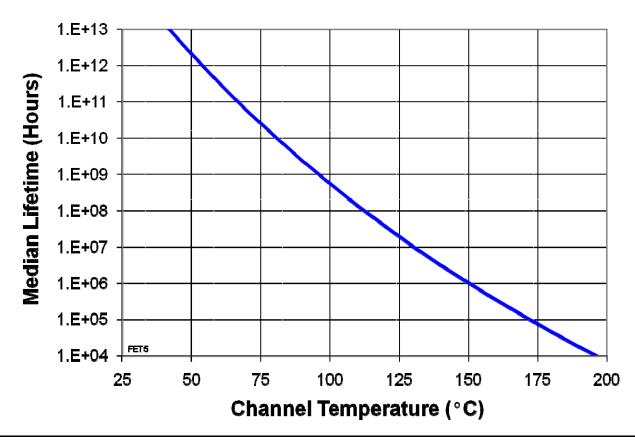


#### TABLE III THERMAL INFORMATION

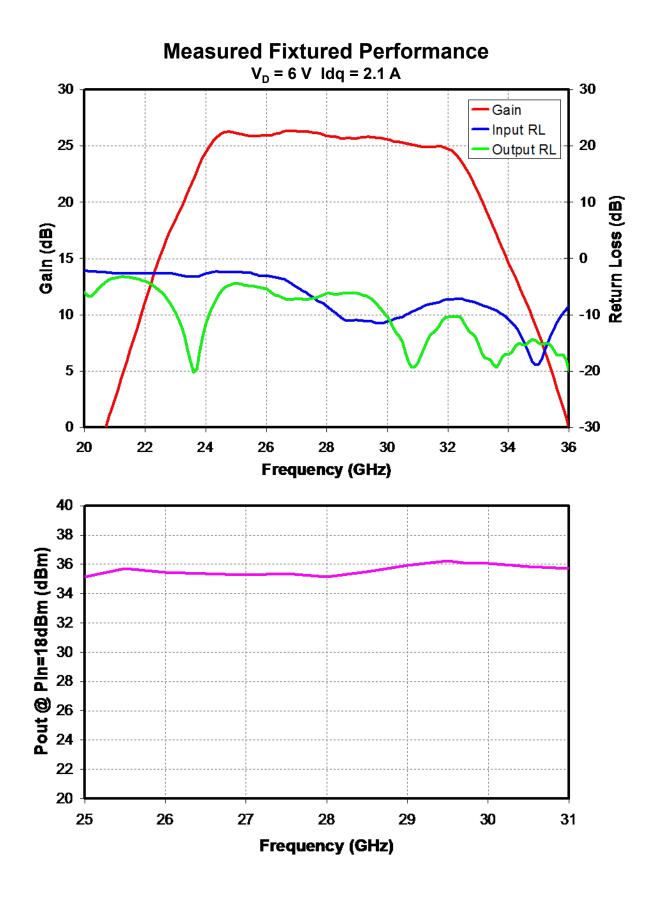
Parameter	Test Conditions	Т <sub>сн</sub> (°С)	θ <sub>JC</sub> (°C/W)	Tm (hrs)
θ <sub>JC</sub> Thermal Resistance (Channel to Backside of Package)	$V_D = 6 V$ $I_D = 2.1 A (Quiescent)$ $P_{DISS} = 12.6 W$	128.35	4.63	6.9 E+6

Note: Backside of package is at 70 °C baseplate temperature. Worst case is at saturated output power when DC power consumption rises to 23 W with 4 W RF power delivered to load. Power dissipated is 19 W and the temperature rise in the channel is 88 °C. The channel temperature is 158 °C assuming a 70 °C baseplate temperature and the median life is 4.4E5 hours.

### Median Lifetime (Tm) vs. Channel Temperature

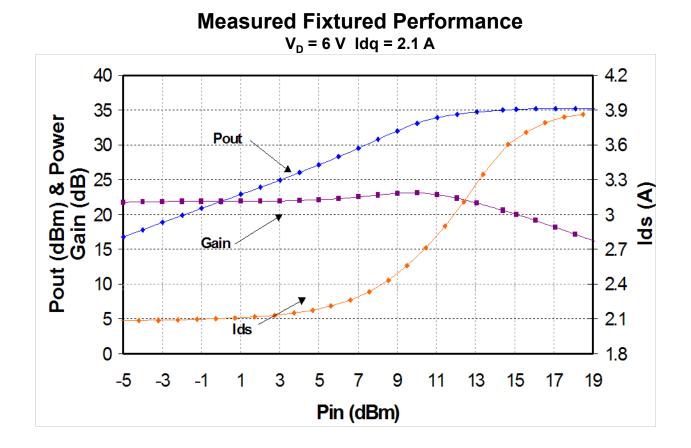








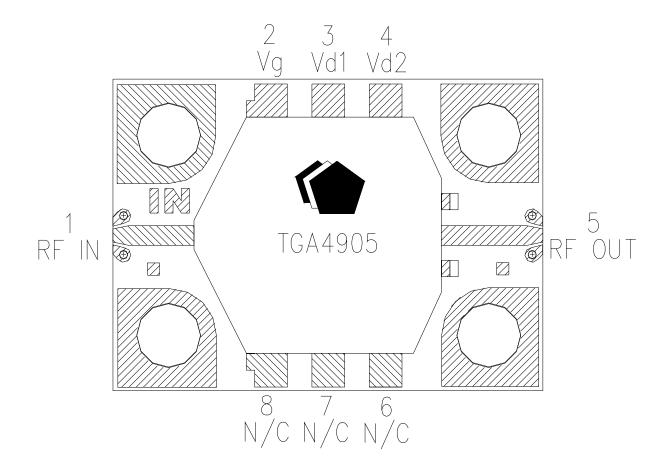






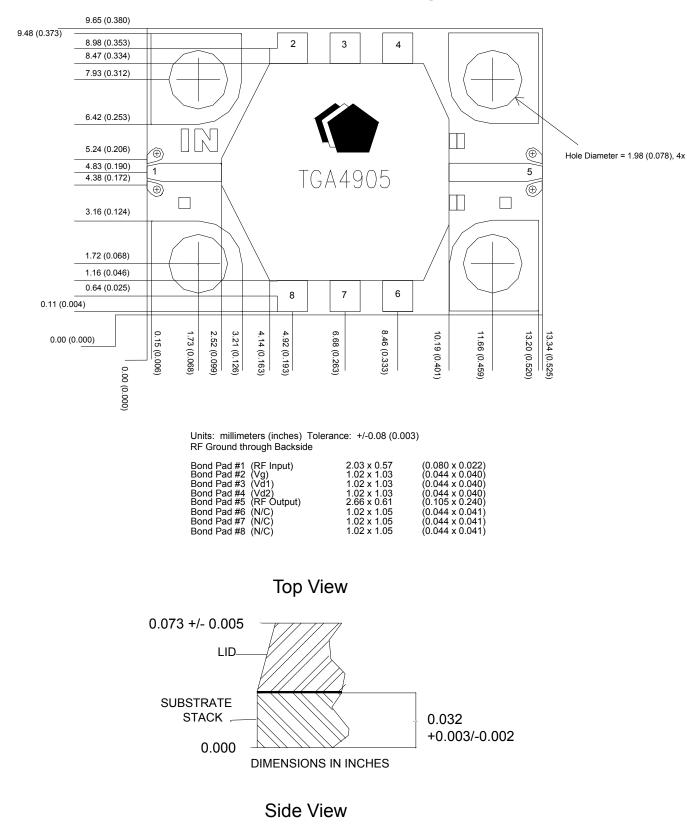


### Package Pinout Diagram



GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.

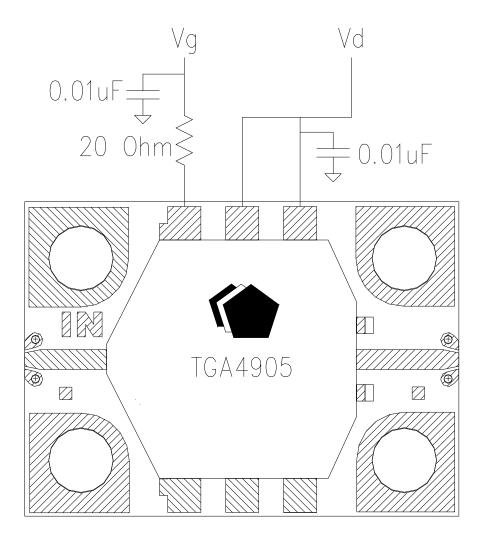




### **Mechanical Drawing**



### **Bias Schematic**



Two 1 mil wires are recommended for the RF Input, RF Output, Vg, and Vd1. Six bondwires are recommended for Vd2.

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#### Assembly of a TGA4905-CP into a Module

#### Manual Assembly for Prototypes

1. Clean the module with Acetone. Rinse with alcohol and DI water. Allow the module to fully dry.

2. To improve the thermal and RF performance, TriQuint recommends attaching a heatsink to the bottom of the package. If the TGA4905 is mounted to the heatsink with mounting screws, an indium shim or other compliant material should be inserted between the TGA4905 and the heatsink to reduce thermal contact resistance due to air gaps. The TGA4905 may also be mounted with DieMat DM6030HK conductive epoxy or an equivalent high thermal conductivity epoxy.

3. The DC and RF interconnects may be gold bondwires or gold ribbons. The RF interconnects should be as short as possible. A minimum of two 1 mil wires are recommended for the RF Input, RF Output, Vg, and Vd1. Six bondwires are recommended for Vd2.

#### ORDERING INFORMATION

PART	PACKAGE STYLE
TGA4905-CP	CARRIER PLATE